

GaAs MMIC Power Amplifier AM009023WM-BM-R AM009023WM-FM-R July 2011 Rev 2



DESCRIPTION

AMCOM's AM009023WM-BM/FM-R is an ultra broadband GaAs MMIC power amplifier. It has 22dB gain, and 25dBm output power over the 0.05 to 9GHz band. The noise figure is 4.5dB up to 4GHz. This MMIC is in a ceramic package with both RF and DC leads at the bottom level of the package to facilitate low-cost SMT assembly to the PC board. The AM009023WM-FM-R is a AM009023WM-BM-R assembled on a gold plated copper flange carrier for screwing on to a metal heat sink. Both parts are RoHS compliant.

FEATURES

- Ultra wide bandwidth from 50MHz to 9GHz
- High output power, P1dB = 25dBm
- High gain, 22dB , low noise
- Input /Output matched to 50 Ohms

APPLICATIONS

- Software Radio
- Instrumentation
- Gain block
- Low Noise applications

TYPICAL PERFORMANCE * (Bias Conditions^{**}: $V_{dd} = +12V$, $I_{dq} = 210$ mA, V_{gs1} , $V_{gs2}=-0.65V$)

| Parameters | Minimum | Typical ** | Maximum |
|-------------------------|------------|-------------|---------|
| Frequency | 0.1 – 8GHz | 0.05 – 9GHz | |
| Small Signal Gain | | 22dB | 25dB |
| Gain Ripple | | ± 3dB | ± 4.0dB |
| P1dB @ 5GHz | 22dBm | 23dBm | |
| P1dB from 0.1 to 8GHz | | > 22dBm | |
| Psat @ 5GHz | 24dBm | 25dBm | |
| Psat from 0.1 to 8.0GHz | | > 23dBm | |
| IP3 @ 1GHz | | 30dBm | |
| Input Return Loss | 3dB | 5dB | |
| Output Return Loss | 7dB | 10dB | |
| Thermal Resistance | | 20°C/W | |

- * Specifications subject to change without notice.
- ** Gate biases corresponding to above currents are V_{gs1} =-0.65V, I_{gs1} < 0.25mA, V_{gs2} =-0.65V, I_{gs2} < 0.5mA and may vary from lot to lot. Gate currents could reach above limits only near power saturation

ABSOLUTE MAXIMUM RATING

| Parameters | Symbol | Rating |
|--------------------------------|-------------------------------------|-----------------|
| Drain source voltage | V _{dd} | 14V |
| Gate source voltage | V _{gs1} & V _{gs2} | -3V |
| Drain source current | I _{dq1} | 0.1A |
| Drain source current | I _{dq2} | 0.20A |
| Continuous dissipation at 25ºC | Pt | 4.2W |
| Channel temperature | T _{ch} | 175°C |
| Operating temperature | T _{op} | -55°C to +85°C |
| Storage temperature | T _{sto} | -55°C to +135°C |

SMALL SIGNAL DATA*



* S-Parameters measured using bias tee at the output for DC block. MMIC could be operated at lower than V_{dd} =+12V with almost same small signal parameters.

POWER DATA*



* Power measured using bias tee at the output for DC block. MMIC could be operated at lower than V_{dd} =+12V with reduced power output.

PACKAGE OUTLINE (BM)



• Gate biases are for reference only and may vary from lot to lot



Pin Layout

| Pin No. | Function | Bias |
|---------|----------|--------|
| 1 | Vdd1 | +12V |
| 2 | NC | |
| 3 | RF in | |
| 4 | NC | |
| 5 | Vgs1 | -0.65V |
| 6 | Vgs2 | -0.65V |
| 7 | NC | |
| 8 | RF out | |
| 9 | NC | |
| 10 | Vdd2 | +12V |

PACKAGE OUTLINE (FM)



Pin Layout



| Pin No. | Function | Bias |
|---------|----------|--------|
| 1 | Vdd1 | +12V |
| 2 | NC | |
| 3 | RF in | |
| 4 | NC | |
| 5 | Vgs1 | -0.65V |
| 6 | Vdd2 | -0.65V |
| 7 | NC | |
| 8 | RF out | |
| 9 | NC | |
| 10 | Vgs2 | +12V |

TEST CIRCUIT for BM Package



4- All Caps & Resistors are 0603 size except for C8: 1206 size

Important Notes:

- 1- Recommended current biases are 70mA and 140mA for the first stage and second stage respectively. Gate biases of -0.65V are for reference only. V_{gs1} & V_{gs2} could be adjusted to vary the currents going thru the first stage (V_{dd1} pin) and the second stage (V_{dd2} pin) respectively.
- 2- Do not apply V_{dd1} & V_{dd2} without proper negative voltages on V_{gs1} & V_{gs2} .
- 3- The currents flowing out of the V_{gs1} & V_{gs2} pins are less than 0.25mA & 0.5mA respectively at P_{1dB} .